# Product Preview

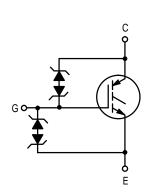
# **Internally Clamped N-Channel IGBT**

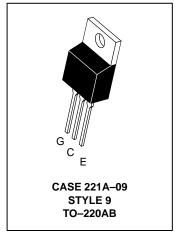
This Logic Level Insulated Gate Bipolar Transistor (IGBT) features Gate–Emitter ESD protection, Gate Collector Over–Voltage Protection from monolithic circuitry for usage as an Ignition Coil Driver.

- Temperature Compensated Gate Collector Clamp Limits Stress Applied to Load
- Integrated ESD Diode Protection
- Low Threshold Voltage to Interface Power Loads to Logic or Microprocessor Devices
- Low Saturation Voltage
- High Pulsed Current Capability



15 AMPERES
N-CHANNEL IGBT
VCE(on) = 1.8 V
380 VOLTS
CLAMPED





### **MAXIMUM RATINGS** (T<sub>.J</sub> = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
Collector–Emitter Voltage	VCES	CLAMPED	Vdc
Collector–Gate Voltage	VCER	CLAMPED	Vdc
Gate–Emitter Voltage	VGE	CLAMPED	Vdc
Collector Current — Continuous	IC	15	Adc
Total Power Dissipation Derate above 25°C	PD	136 0.91	Watts W/°C
Operating and Storage Temperature Range	Т <sub>Ј</sub> , Т <sub>stg</sub>	-55 to 175	°C

### UNCLAMPED COLLECTOR-TO-EMITTER AVALANCHE CHARACTERISTICS (T $_{ m J}$ < 150°C)

Single Pulse Collector–to–Emitter Avalanche Energy	E <sub>AS</sub>		mJ
$V_{CC} = 50 \text{ V}, V_{GE} = 5.0 \text{ V}, PEAK I_{L} = 14.2 \text{ A}, L = 3.0 \text{ mH}, Starting T_{J} = 25^{\circ}C$		300	
$V_{CC} = 50 \text{ V}$ , $V_{GE} = 5.0 \text{ V}$ , PEAK $I_L = 10 \text{ A}$ , $L = 3.0 \text{ mH}$ , Starting $T_J = 150^{\circ}\text{C}$		150	

### THERMAL CHARACTERISTICS

Thermal Resistance — Junction–to–Case — Junction–to–Ambient	R <sub>θJA</sub>	1.1 62.5	°C/W
Maximum Lead Temperature for Soldering Purposes, 1/8" from case for 5 seconds	TL	260	°C

This document contains information on a new product. Specifications and information herein are subject to change without notice.



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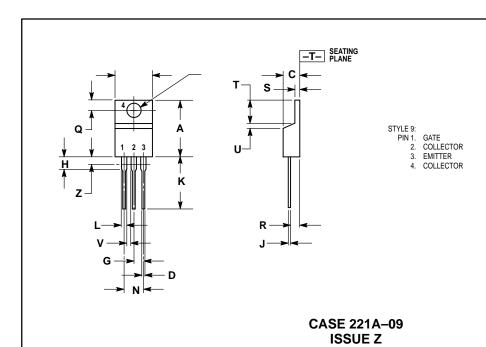
# ELECTRICAL CHARACTERISTICS (T<sub>J</sub> = 25°C unless otherwise noted)

Characteristic		Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS						
Collector–Emitter Clamp Voltage (I <sub>C</sub> = 1.0 mA, T <sub>J</sub> = -40°C to 175°C)		V(BR)CES	350	380	410	Vdc
Zero Gate Voltage Collector Current (VCE = 300 V, VGE = 0 V) (VCE = 300 V, VGE = 0 V, TJ = 150°C)		ICES	_	_	10 150	μAdc
Gate–Emitter Clamp Voltage (IG = 5.0 mA)		V <sub>(BR)</sub> GES	17	_	22	Vdc
Gate–Emitter Leakage Current (VGE = 10 V)		IGES	_	_	10	μAdc
ON CHARACTERISTICS (1)		•		•		
Gate Threshold Voltage  (VGE = VCE, IC = 1.0 mA)  Threshold Temperature Coefficient (Negative)		VGE(th)	1.3 —	1.8 4.4	2.1 —	Vdc mV/°C
Collector-to-Emitter On-Voltage (V <sub>GE</sub> = 3.5 V, I <sub>C</sub> = 6.0 A) (V <sub>GE</sub> = 4.0 V, I <sub>C</sub> = 10 A, T <sub>J</sub> = 150°C)		VCE(on)	_ _	_	2.0 1.8	Volts
Forward Transconductance ( $V_{CE} = 5.0 \text{ V}, I_{C} = 10 \text{ A}$ )		9fe -	8.0	19	_	Mhos
DYNAMIC CHARACTERISTICS						
Input Capacitance		C <sub>ies</sub>	_	TBD	_	pF
Output Capacitance	(V <sub>CC</sub> = 15 V, V <sub>GE</sub> = 0 V, f = 1.0 MHz)	C <sub>oes</sub>	_	TBD	_	
Transfer Capacitance	1	C <sub>res</sub>	_	TBD	_	
SWITCHING CHARACTERISTICS (	1)					
Turn-Off Delay Time	(V <sub>CC</sub> = 300 V, I <sub>C</sub> = 6.5 A,	t <sub>d</sub> (off)	_	TBD	_	μSec
Fall Time	$R_G = 1.0 \text{ k}\Omega, L = 300 \text{ μH}$	t <sub>f</sub>	_	TBD	_	
Turn-On Delay Time	(V <sub>CC</sub> = 10 V, I <sub>C</sub> = 6.5 A,	<sup>t</sup> d(on)	_	TBD	_	μSec
Rise Time	$R_G = 1.0 \text{ k}\Omega, R_L = 1.0 \Omega$	t <sub>r</sub>	_	TBD	_	]
Gate Charge			_	TBD	_	nC
	$(V_{CC} = 300 \text{ V}, I_{C} = 15 \text{ A}, V_{GF} = 5.0 \text{ V})$	Q <sub>1</sub>	_	TBD	_	1
	- GE = 0.0 1/	Q <sub>2</sub>	_	TBD	<u> </u>	1

<sup>(1)</sup> Pulse Test: Pulse Width ≤ 300 μS, Duty Cycle ≤ 2%.

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## **PACKAGE DIMENSIONS**



- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: INCH.
  3. DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.570	0.620	14.48	15.75
В	0.380	0.405	9.66	10.28
С	0.160	0.190	4.07	4.82
D	0.025	0.035	0.64	0.88
F	0.142	0.147	3.61	3.73
G	0.095	0.105	2.42	2.66
Н	0.110	0.155	2.80	3.93
J	0.018	0.025	0.46	0.64
K	0.500	0.562	12.70	14.27
L	0.045	0.060	1.15	1.52
N	0.190	0.210	4.83	5.33
Q	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.045	0.055	1.15	1.39
Т	0.235	0.255	5.97	6.47
U	0.000	0.050	0.00	1.27
٧	0.045		1.15	
Z		0.080		2 04

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